# 3.3 V AnyLevel<sup>™</sup> Receiver to CML Driver/Translator with Input Hysteresis

# 2.0 GHz Clock / 2.5 Gb/s Data

The NB4N316M is a differential Clock or Data receiver and will accept AnyLevel input signals: LVPECL, CML, LVCMOS, LVTTL, or LVDS. These signals will be translated to CML, operating up to 2.0 GHz or 2.5 Gb/s, respectively. As such, the NB4N316M is ideal for SONET, GigE, Fiber Channel, Backplane and other Clock or Data distribution applications. The CML outputs are 16 mA open collector (see Figure 18) which requires resistor ( $R_L$ ) load path to  $V_{TT}$  termination voltage (see Figure 19). The open collector CML outputs must be terminated to  $V_{TT}$  at power up. The differential outputs produce Current–Mode Logic (CML) compatible levels when the receiver is loaded with 50  $\Omega$  or 25  $\Omega$  loads connected to 1.8 V, 2.5 V or 3.3 V supplies. This simplifies device interface by eliminating a need for coupling capacitors.

The NB4N316M features an input threshold hysteresis of approximately 25 mV, providing increased noise immunity and stability.

The device is offered in a small 8-pin TSSOP package (MSOP-8 compatible). Application notes, models, and support documentation are available at <u>www.onsemi.com</u>.

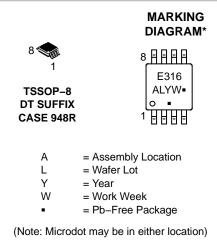
#### Features

- Maximum Input Clock Frequency > 2.0 GHz
- Maximum Input Data Rate > 2.5 Gb/s
- Typically 1 ps of RMS Clock Jitter
- Typically 10 ps of Data Dependent Jitter
- 550 ps Typical Propagation Delay
- 150 ps Typical Rise and Fall Times
- Differential CML Outputs
- 25 mV of Receiver Input Threshold Hysteresis
- Operating Range:  $V_{CC} = 3.0$  V to 3.6 V with  $V_{EE} = 0$  V and  $V_{TT} = 1.8$  V to 3.6 V
- Functionally Compatible with Existing 2.5 V / 3.3 V LVEL, LVEP, EP, and SG Devices
- -40°C to +85°C Ambient Operating Temperature
- These are Pb–Free Devices\*



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\*For additional marking information, refer to Application Note AND8002/D.

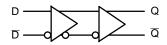


Figure 1. Functional Block Diagram

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 11 of this data sheet.

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

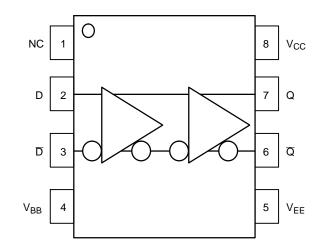


Figure 2. Pinout (Top View) and Logic Diagram

#### Table 1. Pin Description

Pin	Name	I/O	Description			
1	NC	-	No Connect.			
2	D	ECL, CML, LVCMOS, LVDS, LVTTL Input	Noninverted Differential Input. (Note 1)			
3	D	ECL, CML, LVCMOS, LVDS, LVTTL Input	Inverted Differential Input. (Note 1)			
4	V <sub>BB</sub>	-	Internally Generated Reference Voltage Supply.			
5	V <sub>EE</sub>	-	Negative Supply Voltage.			
6	Q	CML Output	Inverted Differential Output. Typically Terminated with 50 $\Omega$ Resistor to V_TT.			
7	Q	CML Output	Noninverted Differential Output. Typically Terminated with 50 $\Omega$ Resistor to V_TT.			
8	V <sub>CC</sub>	-	Positive Supply Voltage.			

1. In the differential configuration if no signal is applied on D/D input, then the device will be susceptible to self-oscillation.

#### **Table 2. ATTRIBUTES**

Characterist	Value					
ESD Protection	Human Body Model Machine Model	> 1000 V > 70 V				
Moisture Sensitivity (Note 1)	8-TSSOP	Level 3				
Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in				
Transistor Count	225					
Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test						

1. For additional information, see Application Note AND8003/D.

#### **Table 3. MAXIMUM RATINGS**

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V <sub>CC</sub>	Positive Power Supply	V <sub>EE</sub> = -0.5 V		4	V
$V_EE$	Negative Power Supply	$V_{CC} = +0.5 V$		-4	V
VI	Positive Input Negative Input	V <sub>EE</sub> = 0 V V <sub>CC</sub> = 0 V	$V_{I} = V_{CC} + 0.4 V$ $V_{I} = V_{EE} - 0.4 V$	4 _4	V V
V <sub>O</sub>	Output Voltage Minimum Maximum			V <sub>EE</sub> + 600 V <sub>CC</sub> + 400	mV mV
T <sub>A</sub>	Operating Temperature Range			-40 to +85	°C
T <sub>stg</sub>	Storage Temperature Range			-65 to +150	°C
$\theta_{JA}$	Thermal Resistance (Junction-to-Ambient) (Note 2)	0 lfpm 500 lfpm	TSSOP-8 TSSOP-8	190 130	°C/W °C/W
$\theta_{\text{JC}}$	Thermal Resistance (Junction-to-Case)	1S2P (Note 2)	TSSOP-8	41 to 44	°C/W
T <sub>sol</sub>	Wave Solder	< 3 Sec @ 260°C		265	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.
JEDEC standard multilayer board – 1S2P (1 signal, 2 power) with 8 filled thermal vias under exposed pad.

Symbol	Characteristic	Min	Тур	Max	Unit
I <sub>CC</sub>	Power Supply Current (Inputs and Outputs Open)		20	30	mA
R <sub>L</sub> = 50 Ω,	V <sub>TT</sub> = 3.6 V to 2.5 V				
V <sub>OH</sub>	Output HIGH Voltage (Note 3)	V <sub>TT</sub> – 60	V <sub>TT</sub> – 10	V <sub>TT</sub>	mV
V <sub>OL</sub>	Output LOW Voltage (Note 3)	V <sub>TT</sub> – 1100	V <sub>TT</sub> – 800	V <sub>TT</sub> – 640	mV
V <sub>OD</sub>	Differential Output Voltage Magnitude	640	780	1000	mV
R <sub>L</sub> = 25 Ω,	V <sub>TT</sub> = 3.6 V to 2.5 V ±5%				
V <sub>OH</sub>	Output HIGH Voltage (Note 3)	V <sub>TT</sub> – 60	V <sub>TT</sub> – 10	V <sub>TT</sub>	mV
V <sub>OL</sub>	Output LOW Voltage (Note 3)	V <sub>TT</sub> – 550	V <sub>TT</sub> – 400	V <sub>TT</sub> – 320	mV
V <sub>OD</sub>	Differential Output Voltage Magnitude	320	390	500	mV
R <sub>L</sub> = 50 Ω,	$V_{TT} = 1.8 V \pm 5\%$				
V <sub>OH</sub>	Output HIGH Voltage (Note 3)	V <sub>TT</sub> – 170	V <sub>TT</sub> – 10	V <sub>TT</sub>	mV
V <sub>OL</sub>	Output LOW Voltage (Note 3)	V <sub>TT</sub> – 1100	V <sub>TT</sub> – 800	V <sub>TT</sub> – 640	mV
V <sub>OD</sub>	Differential Output Voltage Magnitude	570	780	1000	mV
R <sub>L</sub> = 25 Ω,	V <sub>TT</sub> = 1.8 V ±5%				
V <sub>OH</sub>	Output HIGH Voltage (Note 3)	V <sub>TT</sub> – 85	V <sub>TT</sub> – 10	V <sub>TT</sub>	mV
V <sub>OL</sub>	Output LOW Voltage (Note 3)	V <sub>TT</sub> – 500	V <sub>TT</sub> – 400	V <sub>TT</sub> – 320	mV
V <sub>OD</sub>	Differential Output Voltage Magnitude	285	390	500	mV
DIFFEREN	TIAL INPUT DRIVEN SINGLE-ENDED (Figures 14 and 16)				
V <sub>th</sub>	Input Threshold Reference Voltage Range (Note 5)	V <sub>EE</sub>		V <sub>CC</sub>	mV
V <sub>IH</sub>	Single-ended Input HIGH Voltage	V <sub>th</sub> + 100		V <sub>CC</sub> + 400	mV
V <sub>IL</sub>	Single-ended Input LOW Voltage	V <sub>EE</sub> – 400		V <sub>th</sub> – 100	mV
$V_{BB}$	Internally Generated Reference Voltage Supply (Loaded with –100 $\mu\text{A})$	V <sub>CC</sub> – 1500	V <sub>CC</sub> – 1400	V <sub>CC</sub> – 1300	mV
DIFFEREN	TIAL INPUTS DRIVEN DIFFERENTIALLY (Figures 15 and 17)				
V <sub>IHD</sub>	Differential Input HIGH Voltage	V <sub>EE</sub>		V <sub>CC</sub> + 400	mV
V <sub>ILD</sub>	Differential Input LOW Voltage	V <sub>EE</sub> – 400		V <sub>CC</sub> – 100	mV
V <sub>CMR</sub>	Input Common Mode Range (Differential Configuration)	V <sub>EE</sub>		V <sub>CC</sub>	mV
V <sub>ID(HYST)</sub>	Differential Input Voltage Hysteresis (V <sub>IHD</sub> – V <sub>ILD</sub> )		25		mV
V <sub>ID</sub>	Differential Input Voltage Magnitude ( V <sub>IHD</sub> – V <sub>ILD</sub>  ) (Note 7)	100		$V_{CC} - V_{EE}$	mV
C <sub>IN</sub>	Input Capacitance (Note 7)		1.5		pF

Table 4 DC CHARACTERISTICS CLOCK Innuts CMI Outputs V 2 0 1/ 42 2 0 1/ 1/ 4000 to 1000

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

CML outputs require R<sub>L</sub> receiver termination resistors to V<sub>TT</sub> for proper operation. Outputs must be connected through R<sub>L</sub> to V<sub>TT</sub> at power up. The output parameters vary 1:1 with V<sub>TT</sub>. V<sub>TT</sub> = 1.71 V to 3.6 V.
 Input parameters vary 1:1 with V<sub>CC</sub>.
 V<sub>th</sub> is applied to the complementary input when operating in single–ended mode.
 V<sub>CMR</sub> (MIN) varies 1:1 with V<sub>EE</sub>, V<sub>CMR</sub> max varies 1:1 with V<sub>CC</sub>.
 Parameter guaranteed by design and evaluation but not tested in production.

		-40°C		25°C			85°C				
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
V <sub>OUTPP</sub>	$\begin{array}{l} \text{Output Voltage Amplitude } (\text{R}_{\text{L}} = 50 \ \Omega) \\ & f_{\text{in}} \leq 1 \ \text{GHz} \\ \text{(See Figure 12)} \\ & f_{\text{in}} \leq 1.5 \ \text{GHz} \\ & f_{\text{in}} \leq 2.0 \ \text{GHz} \end{array}$	550 400 200	660 640 400		550 400 200	660 640 400		550 400 200	660 640 400		mV
V <sub>OUTPP</sub>	$\begin{array}{l} \mbox{Output Voltage Amplitude } (R_L = 25 \ \Omega) \\ f_{in} \leq 1 \ GHz \\ (See \ Figure \ 12) \\ f_{in} \leq 1.5 \ GHz \\ f_{in} \leq 2.0 \ GHz \end{array}$	280 280 200	370 360 300		280 280 200	370 360 400		280 280 200	370 360 400		mV
f <sub>DATA</sub>	Maximum Operating Data Rate	1.5	2.5		1.5	2.5		1.5	2.5		Gb/s
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay to Output Differential @ 0.25 GHz	350	550	750	350	550	750	350	550	750	ps
t <sub>SKEW</sub>	Duty Cycle Skew (Note 9) Device to Device Skew (Note 13)		2 20	20 100		2 20	20 100		2 20	20 100	ps
ţjitter	$\begin{array}{l} \text{RMS Random Clock Jitter } \text{R}_{L} = 50 \ \Omega \text{ and} \\ \text{R}_{L} = 25 \ \Omega \text{ (Note 11)} & f_{in} = 750 \ \text{MHz} \\ f_{in} = 1.5 \ \text{GHz} \\ f_{in} = 2.0 \ \text{GHz} \\ \text{Peak-to-Peak Data Dependent Jitter } \text{R}_{L} = 50 \ \Omega \\ \text{f}_{DATA} = 1.5 \ \text{Gb/s} \\ \text{(Note 12)} & f_{DATA} = 2.5 \ \text{Gb/s} \\ \text{Peak-to-Peak Data Dependent Jitter } \text{R}_{L} = 25 \ \Omega \\ f_{DATA} = 1.5 \ \text{Gb/s} \\ \text{(Note 12)} & f_{DATA} = 2.5 \ \text{Gb/s} \\ \text{(Note 12)} & f_{DATA} = 2.5 \ \text{Gb/s} \\ \end{array}$		1 1 15 20 5 10	3 3 55 85 35 35		1 1 15 20 5 10	3 3 55 85 35 35		1 1 15 20 5 10	3 3 55 85 35 35	ps
V <sub>INPP</sub>	Input Voltage Swing/Sensitivity (Differential Configuration) (Note 10)	200			200			200			mV
t <sub>r</sub> t <sub>f</sub>	Output Rise/Fall Times @ 0.25 GHz Q, Q (20% - 80%)		150	300		150	300		150	300	ps

#### Table 5. AC CHARACTERISTICS V<sub>CC</sub> = 3.0 V to 3.6 V, V<sub>EE</sub> = 0 V; (Note 8)

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

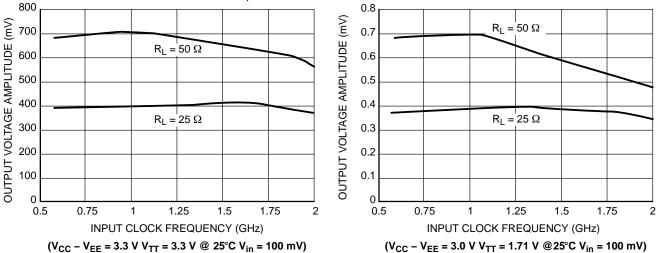
8. Measured by forcing V<sub>INPP</sub> (MIN) from a 50% duty cycle clock source. All output loaded with an external R<sub>L</sub> = 50  $\Omega$  and R<sub>L</sub> = 25  $\Omega$  to V<sub>TT</sub>. Outputs must be connected through RL to VTT at power up. Input edge rates 150 ps (20% - 80%).

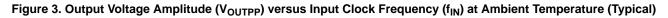
9. Duty cycle skew is measured between differential outputs using the deviations of the sum of  $T_{pw-}$  and  $T_{pw+}$  @ 0.25 GHz. 10.  $V_{INPP}$  (MAX) cannot exceed  $V_{CC} - V_{EE}$ . Input voltage swing is a single-ended measurement operating in differential mode.

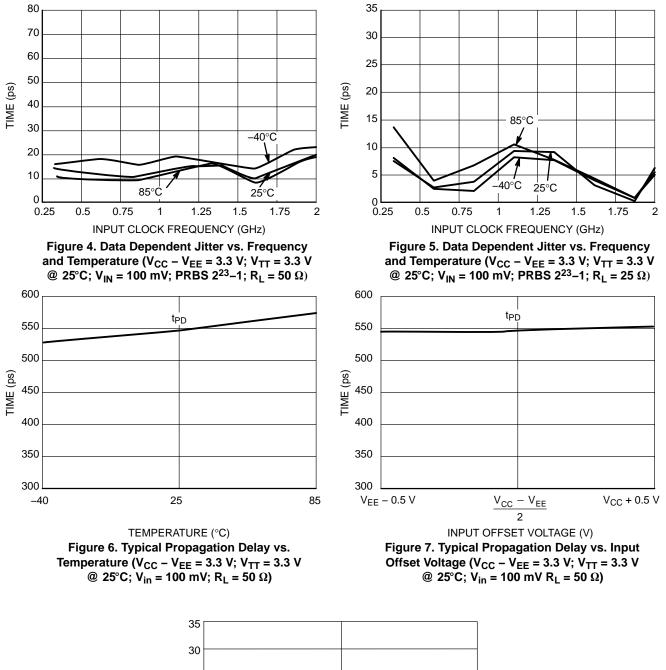
11. Additive RMS jitter with 50% duty cycle clock signal.

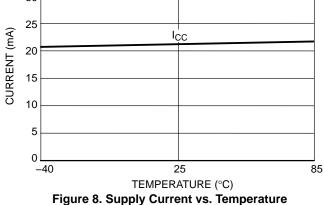
12. Additive peak-to-peak data dependent jitter with input NRZ data signal (PRBS 2<sup>23</sup>-1).

13. Device to device skew is measured between outputs under identical transition @ 0.5 GHz.









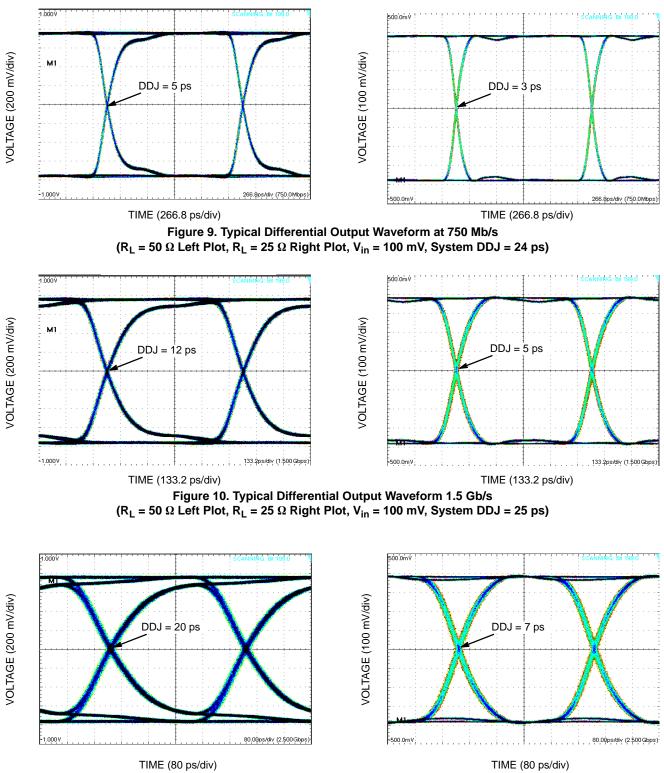
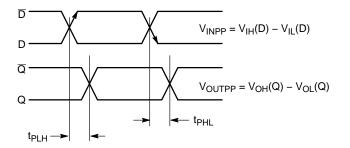


Figure 11. Typical Differential Output Waveform 2.5 Gb/s ( $R_L$  = 50  $\Omega$  Left Plot,  $R_L$  = 25  $\Omega$  Right Plot,  $V_{in}$  = 100 mV, System DDJ = 24 ps)





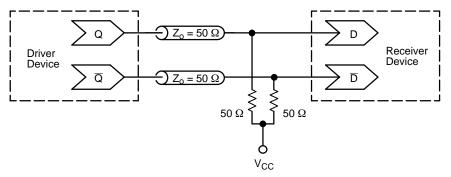


Figure 13. Typical Termination for Output Driver and Device Evaluation (See Application Note AND8020/D – Termination of ECL Logic Devices.)

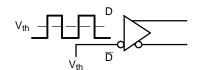


Figure 14. Differential Input Driven Single–Ended

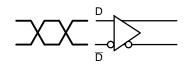
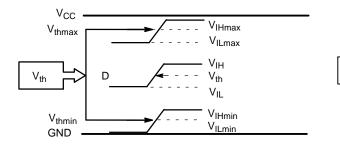
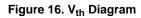
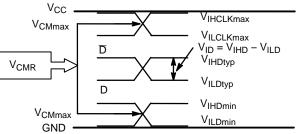
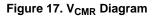


Figure 15. Differential Inputs Driven Differentially









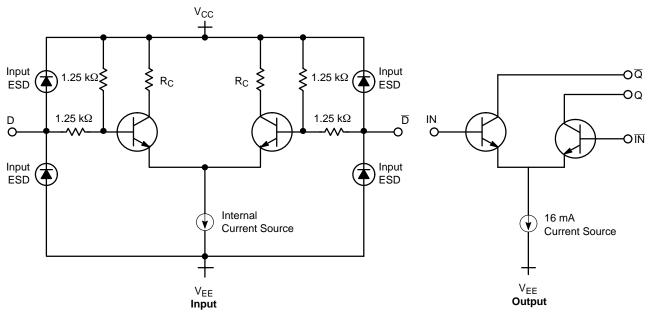


Figure 18. CML Input and Output Structure

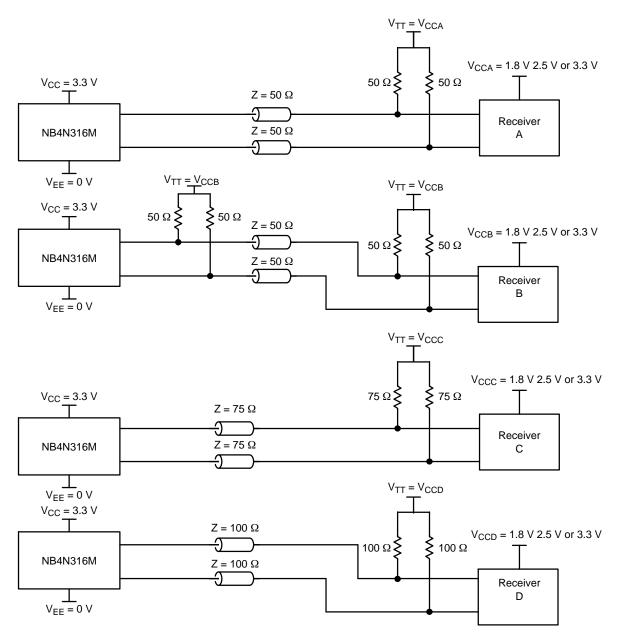


Figure 19. Typical Examples of the Application Interface

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>		
NB4N316MDTG	TSSOP–8 (Pb–Free)	100 Units / Rail		
NB4N316MDTR2G	TSSOP–8 (Pb–Free)	2500 / Tape & Reel		

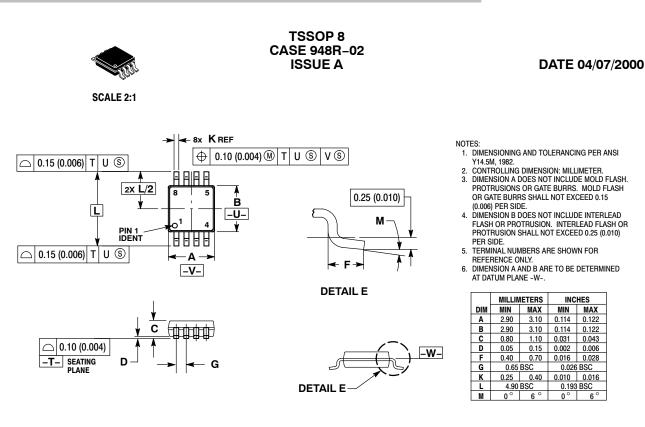
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### **Resource Reference of Application Notes**

AN1405/D	-	ECL Clock Distribution Techniques
AN1406/D	_	Designing with PECL (ECL at +5.0 V)
AN1503/D	_	ECLinPS <sup>™</sup> I/O SPiCE Modeling Kit
AN1504/D	_	Metastability and the ECLinPS Family
AN1568/D	_	Interfacing Between LVDS and ECL
AN1672/D	_	The ECL Translator Guide
AND8001/D	_	Odd Number Counters Design
AND8002/D	_	Marking and Date Codes
AND8020/D	_	Termination of ECL Logic Devices
AND8066/D	_	Interfacing with ECLinPS
AND8090/D	_	AC Characteristics of ECL Devices

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